

# M66256FP

5120 × 8-BIT LINE MEMORY (FIFO)

## DESCRIPTION

The M66256FP is a high-speed line memory with a FIFO (First In First Out) structure of 5120-word × 8-bit configuration which uses high-performance silicon gate CMOS process technology.

It has separate clock, enable and reset signals for write and read, and is most suitable as a buffer memory between devices with different data processing throughput.

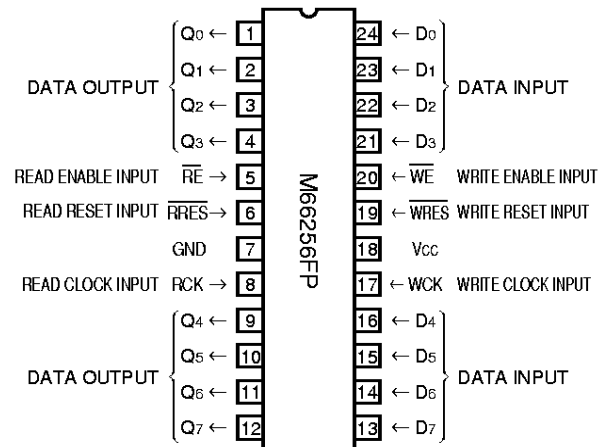
## FEATURES

- Memory configuration ..... 5120 words × 8-bits (dynamic memory)
- High-speed cycle ..... 25ns (Min.)
- High-speed access ..... 18ns (Max.)
- Output hold ..... 3ns (Min.)
- Fully independent, asynchronous write and read operations
- Variable length delay bit
- Output ..... 3 states

## APPLICATION

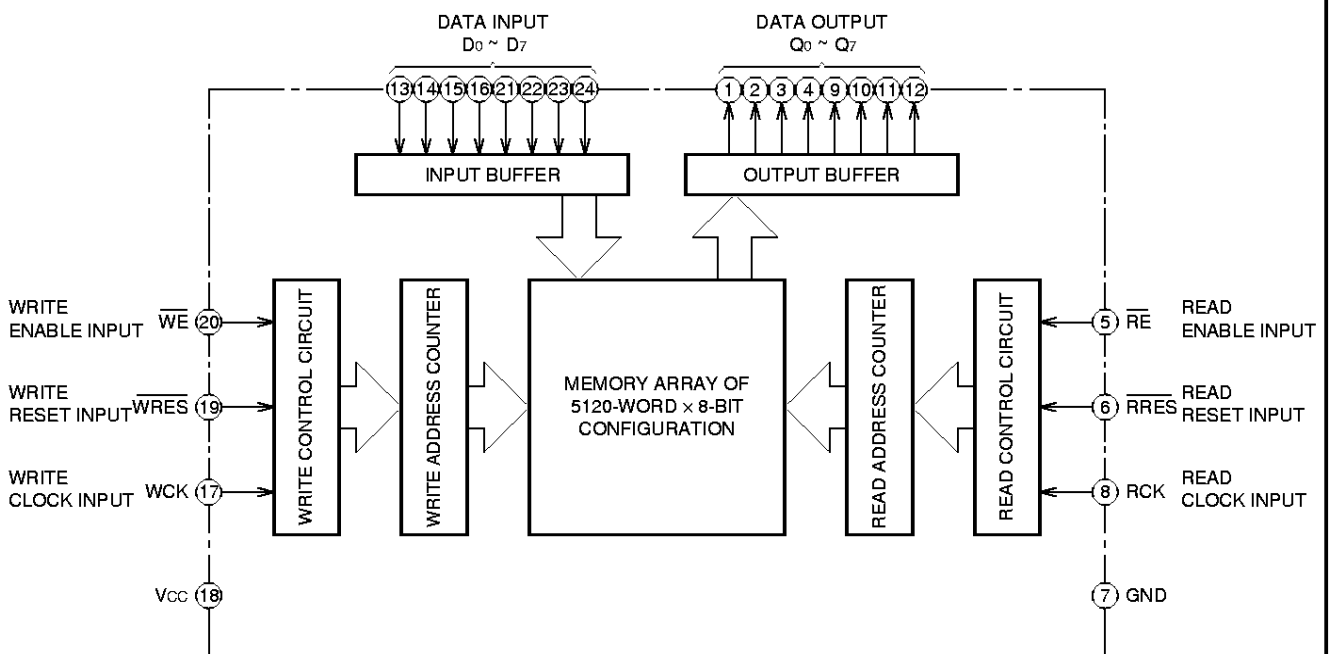
Digital photocopiers, high-speed facsimile, laser beam printers.

## PIN CONFIGURATION (TOP VIEW)



Outline 24P2U-A

## BLOCK DIAGRAM



## FUNCTION

When write enable input  $\overline{WE}$  is "L", the contents of data inputs D0 to D7 are written into memory in synchronization with rise edge of write clock input WCK. At this time, the write address counter is also incremented simultaneously.

The write function given below are also performed in synchronization with rise edge of WCK.

When  $\overline{WE}$  is "H", a write operation to memory is inhibited and the write address counter is stopped.

When write reset input WRES is "L", the write address counter is initialized.

When read enable input  $\overline{RE}$  is "L", the contents of memory are output to data outputs Q0 to Q7 in synchronization with rise edge of read clock input RCK. At this time, the read address counter is also incremented simultaneously.

The read functions given below are also performed in synchronization with rise edge of RCK.

When  $\overline{RE}$  is "H", a read operation from memory is inhibited and the read address counter is stopped. The outputs are in the high impedance state.

When read reset input RRES is "L", the read address counter is initialized.

## ABSOLUTE MAXIMUM RATINGS (Ta = 0 ~ 70°C, unless otherwise noted)

| Symbol | Parameter                 | Conditions               | Ratings          | Unit |
|--------|---------------------------|--------------------------|------------------|------|
| VCC    | Supply voltage            | A value based on GND pin | -0.5 ~ +7.0      | V    |
| VI     | Input voltage             |                          | -0.5 ~ VCC + 0.5 | V    |
| VO     | Output voltage            |                          | -0.5 ~ VCC + 0.5 | V    |
| Pd     | Maximum power dissipation | Ta = 25°C                | 440              | mW   |
| Tsig   | Storage temperature       |                          | -65 ~ 150        | °C   |

## RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter                     | Limits |      |      | Unit |
|--------|-------------------------------|--------|------|------|------|
|        |                               | Min.   | Typ. | Max. |      |
| VCC    | Supply voltage                | 4.5    | 5    | 5.5  | V    |
| GND    | Supply voltage                |        | 0    |      | V    |
| Topr   | Operating ambient temperature | 0      |      | 70   | °C   |

## ELECTRICAL CHARACTERISTICS (Ta = 0 ~ 70°C, VCC = 5V ± 10%, GND = 0V)

| Symbol | Parameter                          | Test conditions                                 | Limits                                |      |         | Unit |
|--------|------------------------------------|-------------------------------------------------|---------------------------------------|------|---------|------|
|        |                                    |                                                 | Min.                                  | Typ. | Max.    |      |
| VIH    | "H" input voltage                  |                                                 | 2.0                                   |      |         | V    |
| VIL    | "L" input voltage                  |                                                 |                                       |      | 0.8     | V    |
| VOH    | "H" output voltage                 | IOH = -4mA                                      |                                       |      | VCC-0.8 | V    |
| VOL    | "L" output voltage                 | IOL = 4mA                                       |                                       |      | 0.55    | V    |
| IIH    | "H" input current                  | VI = VCC                                        | WE, WRES, WCK, RE, RRES, RCK, D0 ~ D7 |      | 1.0     | μA   |
| IIL    | "L" input current                  | VI = GND                                        | WE, WRES, WCK, RE, RRES, RCK, D0 ~ D7 |      | -1.0    | μA   |
| IOZH   | Off state "H" output current       | VO = VCC                                        |                                       |      | 5.0     | μA   |
| IOZL   | Off state "L" output current       | VO = GND                                        |                                       |      | -5.0    | μA   |
| ICC    | Operating mean current dissipation | VI = VCC, GND, Output open<br>twck, trck = 25ns |                                       |      | 80      | mA   |
| CI     | Input capacitance                  | f = 1MHz                                        |                                       |      | 10      | pF   |
| CO     | Off state output capacitance       | f = 1MHz                                        |                                       |      | 15      | pF   |

**SWITCHING CHARACTERISTICS** ( $T_a = 0 \sim 70^\circ\text{C}$ ,  $V_{CC} = 5V \pm 10\%$ ,  $GND = 0V$ )

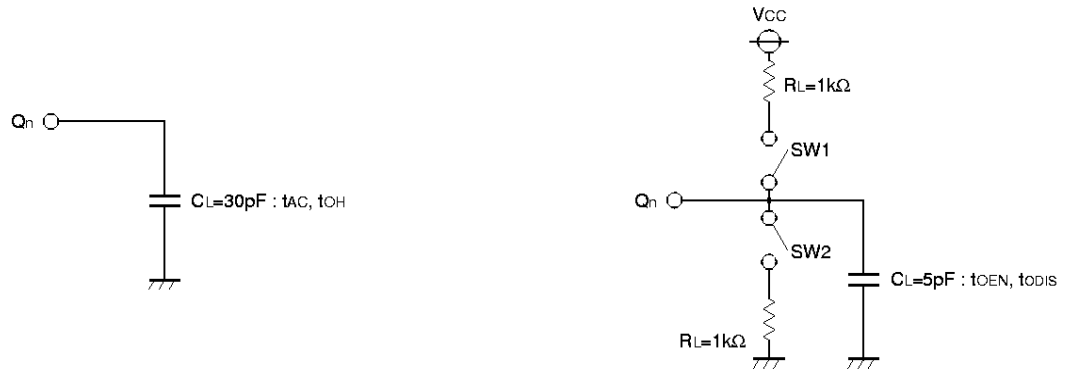
| Symbol | Parameter           | Limits |      |      | Unit |
|--------|---------------------|--------|------|------|------|
|        |                     | Min.   | Typ. | Max. |      |
| tAC    | Access time         |        |      | 18   | ns   |
| tOH    | Output hold time    | 3      |      |      | ns   |
| tOEN   | Output enable time  | 3      |      | 18   | ns   |
| tODIS  | Output disable time | 3      |      | 18   | ns   |

**TIMING CONDITIONS** ( $T_a = 0 \sim 70^\circ\text{C}$ ,  $V_{CC} = 5V \pm 10\%$ ,  $GND = 0V$ , unless otherwise noted)

| Symbol                          | Parameter                                   | Limits |      |      | Unit |
|---------------------------------|---------------------------------------------|--------|------|------|------|
|                                 |                                             | Min.   | Typ. | Max. |      |
| tWCK                            | Write clock (WCK) cycle                     | 25     |      |      | ns   |
| tWCKH                           | Write clock (WCK) "H" pulse width           | 11     |      |      | ns   |
| tWCKL                           | Write clock (WCK) "L" pulse width           | 11     |      |      | ns   |
| tRCK                            | Read clock (RCK) cycle                      | 25     |      |      | ns   |
| tRCKH                           | Read clock (RCK) "H" pulse width            | 11     |      |      | ns   |
| tRCKL                           | Read clock (RCK) "L" pulse width            | 11     |      |      | ns   |
| tDS                             | Input data setup time to WCK                | 7      |      |      | ns   |
| tDH                             | Input data hold time to WCK                 | 3      |      |      | ns   |
| tRESS                           | Reset setup time to WCK or RCK              | 7      |      |      | ns   |
| tRESH                           | Reset hold time to WCK or RCK               | 3      |      |      | ns   |
| tNRESS                          | Reset nonselect setup time to WCK or RCK    | 7      |      |      | ns   |
| tNRESH                          | Reset nonselect hold time to WCK or RCK     | 3      |      |      | ns   |
| tWES                            | $\overline{WE}$ setup time to WCK           | 7      |      |      | ns   |
| tWEH                            | $\overline{WE}$ hold time to WCK            | 3      |      |      | ns   |
| tNWES                           | $\overline{WE}$ nonselect setup time to WCK | 7      |      |      | ns   |
| tNWEH                           | $\overline{WE}$ nonselect hold time to WCK  | 3      |      |      | ns   |
| tRES                            | $\overline{RE}$ setup time to RCK           | 7      |      |      | ns   |
| tREH                            | $\overline{RE}$ hold time to RCK            | 3      |      |      | ns   |
| tNRES                           | $\overline{RE}$ nonselect setup time to RCK | 7      |      |      | ns   |
| tNREH                           | $\overline{RE}$ nonselect hold time to RCK  | 3      |      |      | ns   |
| t <sub>r</sub> , t <sub>f</sub> | Input pulse rise/fall time                  |        |      | 20   | ns   |
| tH                              | Data hold time (Note 1)                     |        |      | 20   | ms   |

Notes 1: For 1-line access, the following should be satisfied:  
 $\overline{WE}$  "H" level period  $\leq 20\text{ms} - 5120 t_{WCK} - \overline{WRES}$  "L" level period  
 $\overline{RE}$  "H" level period  $\leq 20\text{ms} - 5120 t_{RCK} - \overline{RRES}$  "L" level period  
2: Perform reset operation after turning on power supply.

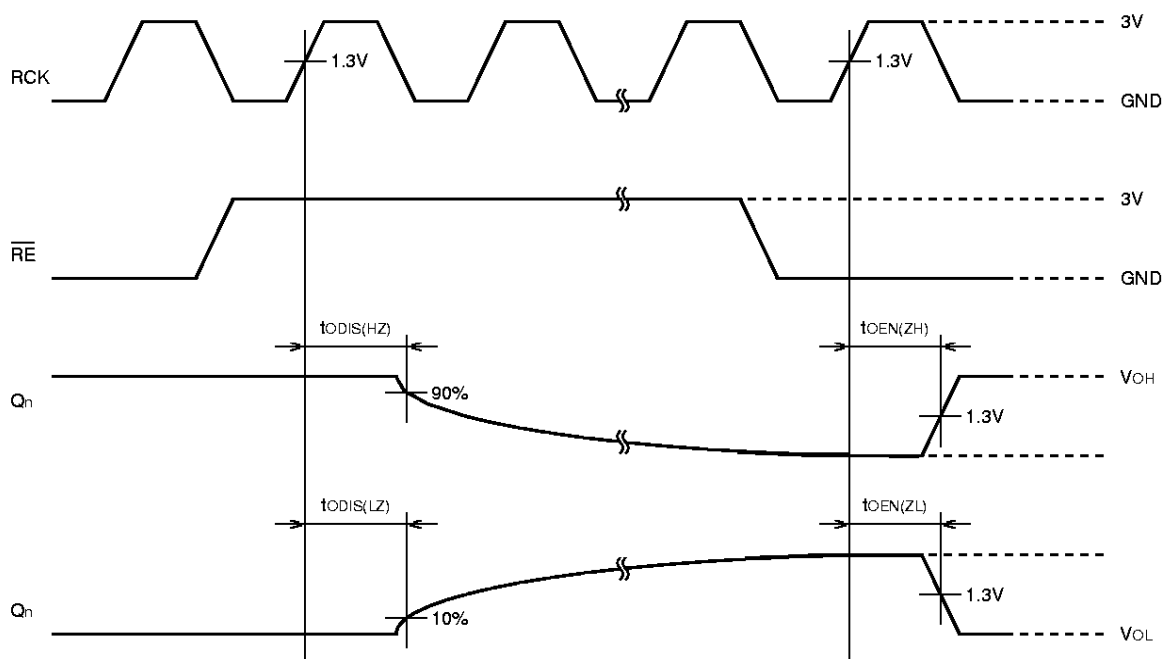
# TEST CIRCUIT



Input pulse level : 0 ~ 3V  
 Input pulse rise/fall time : 3ns  
 Decision voltage input : 1.3V  
 Decision voltage output : 1.3V (However,  $t_{ODIS(LZ)}$  is 10% of output amplitude and  $t_{ODIS(HZ)}$  is 90% of that for decision).  
 The load capacitance  $C_L$  includes the floating capacitance of connection and the input capacitance of probe.

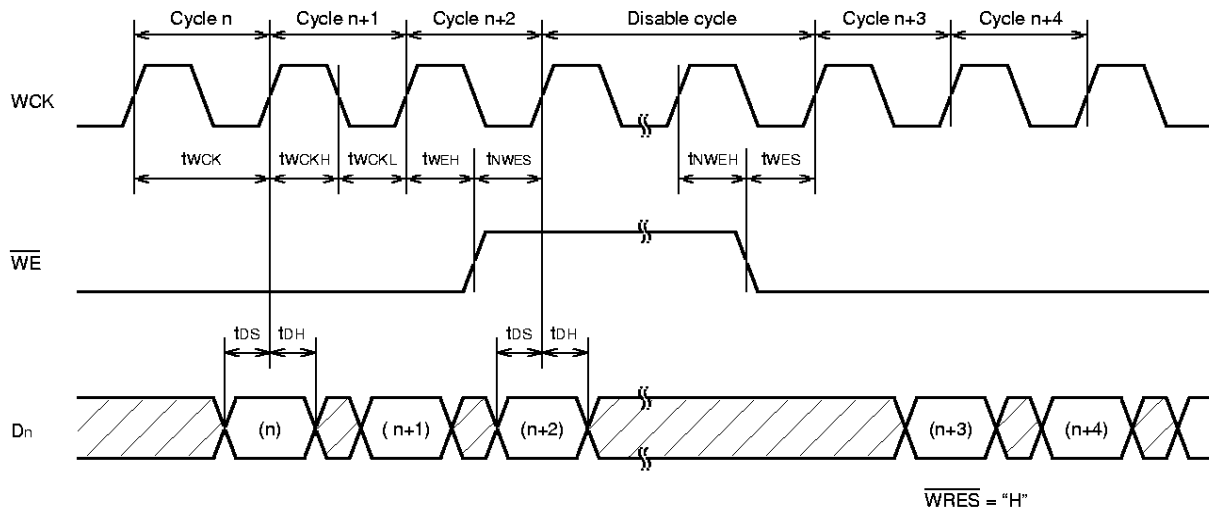
| Parameter      | SW1    | SW2    |
|----------------|--------|--------|
| $t_{ODIS(LZ)}$ | Closed | Open   |
| $t_{ODIS(HZ)}$ | Open   | Closed |
| $t_{OEN(ZL)}$  | Closed | Open   |
| $t_{OEN(ZH)}$  | Open   | Closed |

# $t_{ODIS}/t_{OEN}$ TEST CONDITION

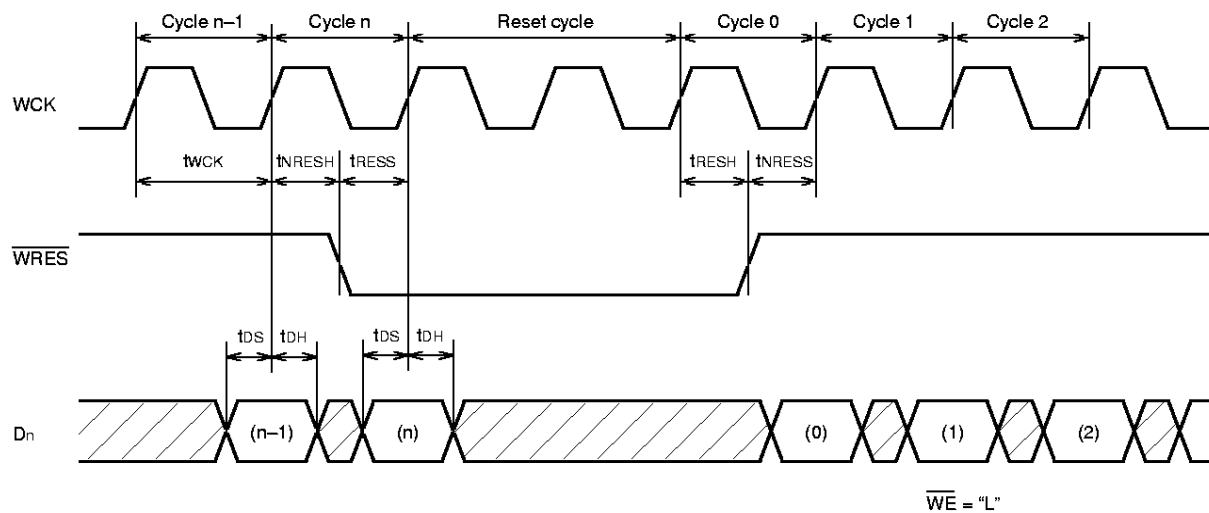


## OPERATING TIMING

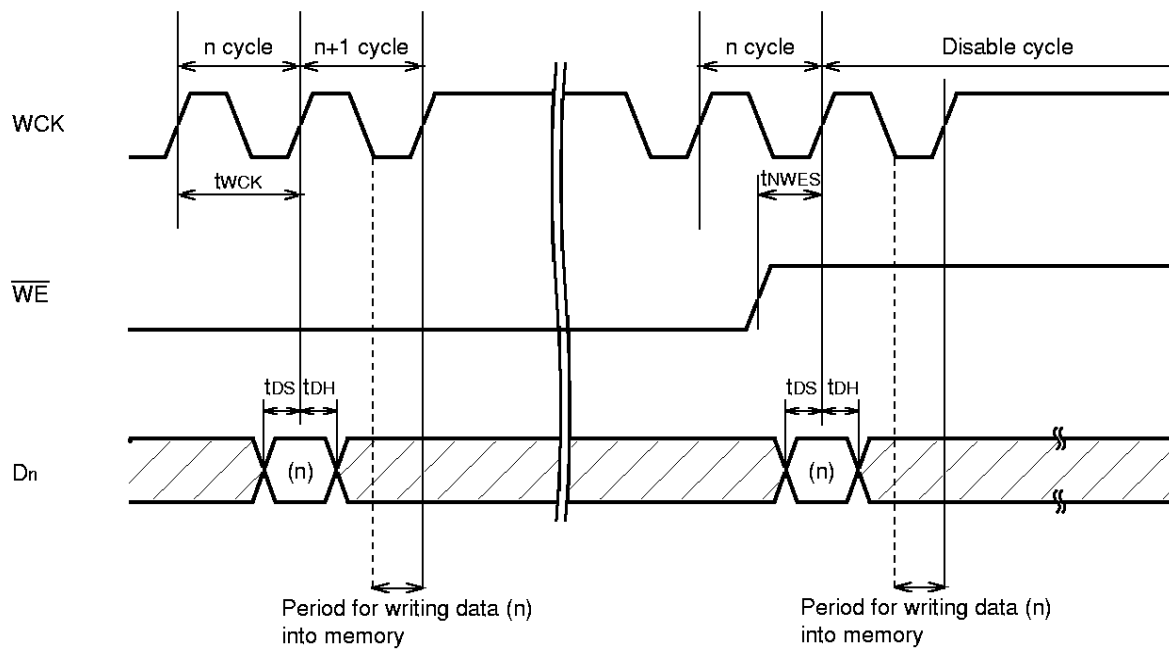
### • Write cycle



### • Write reset cycle



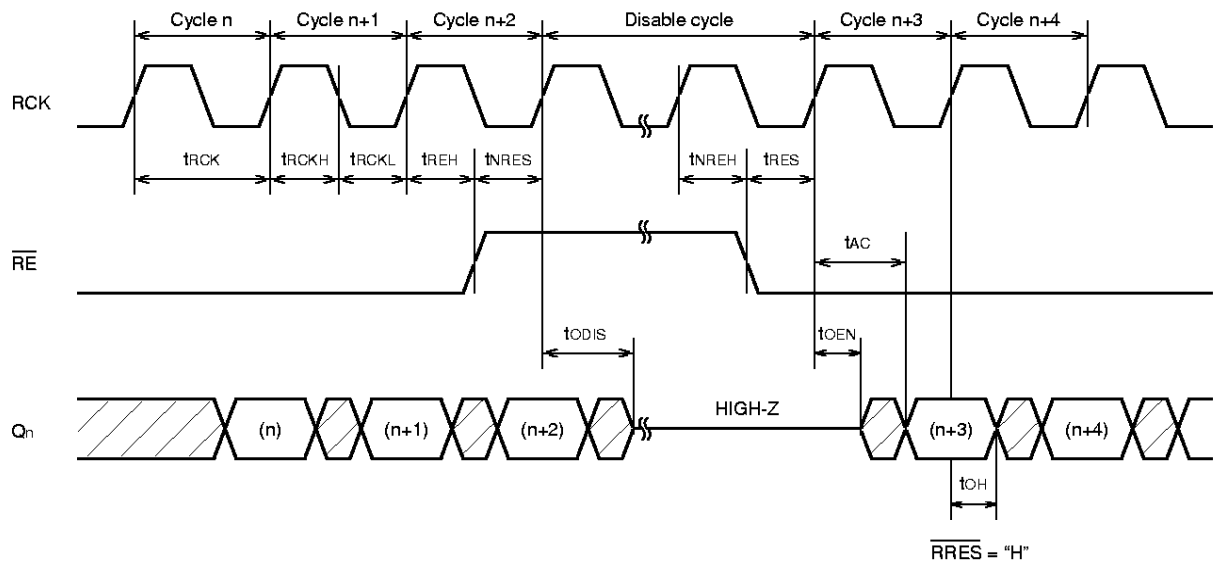
- Matters that needs attention when WCK stops



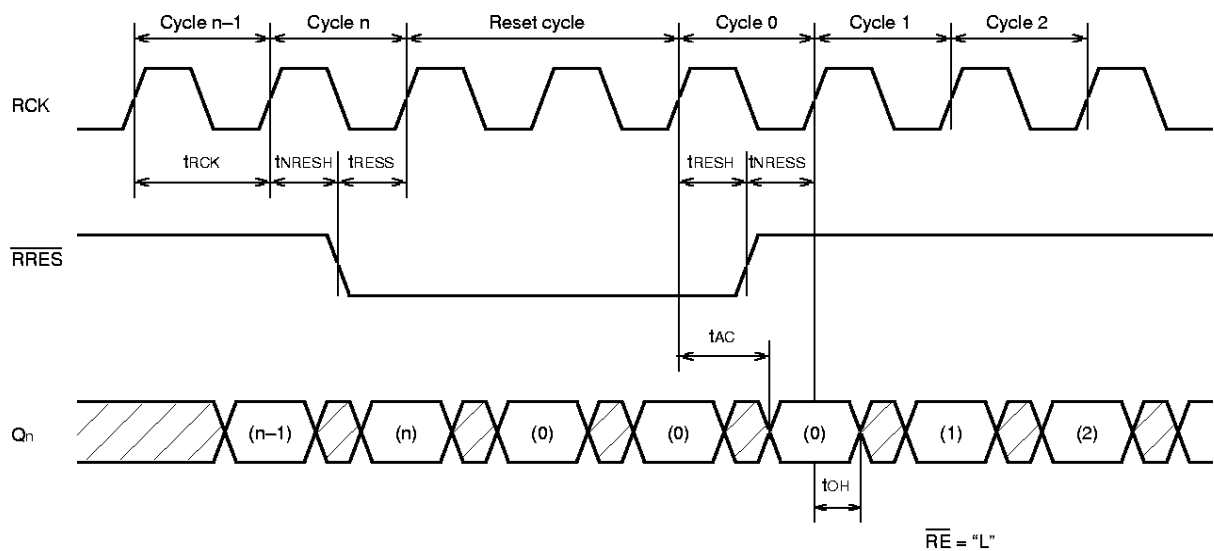
$\overline{WRES} = "H"$

Input data of n cycle is read at the rising edge after WCK of n cycle and writing operation starts in the WCK low-level period of n+1 cycle. The writing operation is complete at the falling edge after n+1 cycle. To stop reading write data at n cycle, enter WCK before the rising edge after n+1 cycle. When the cycle next to n cycle is a disable cycle, WCK for a cycle requires to be entered after the disable cycle as well.

• Read cycle



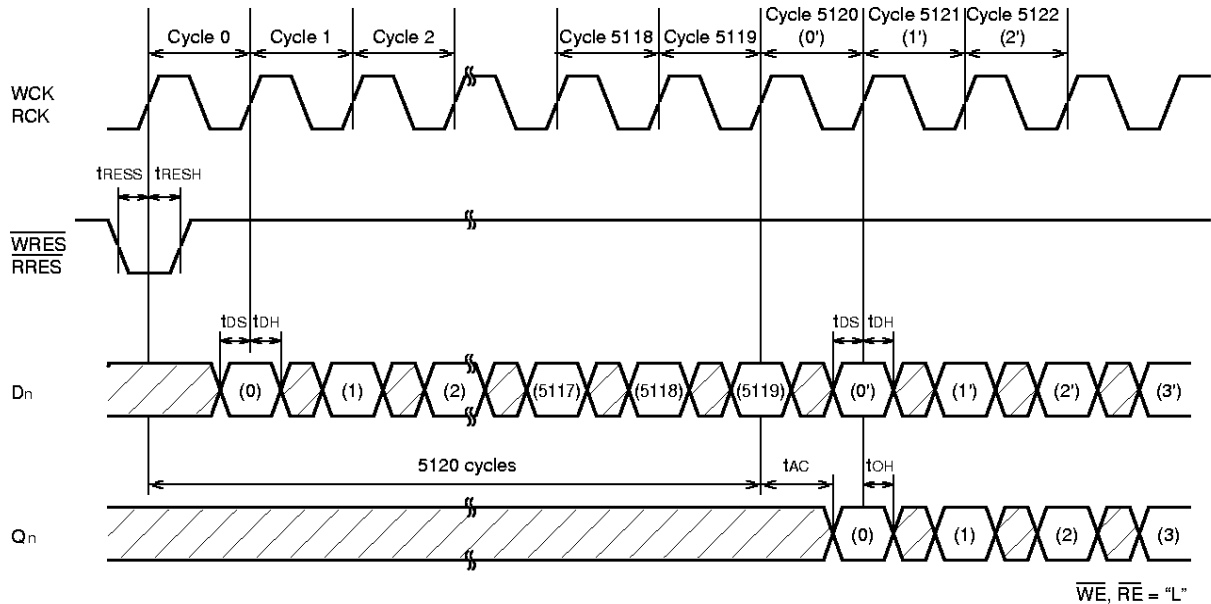
• Read reset cycle



### VARIABLE LENGTH DELAY BITS

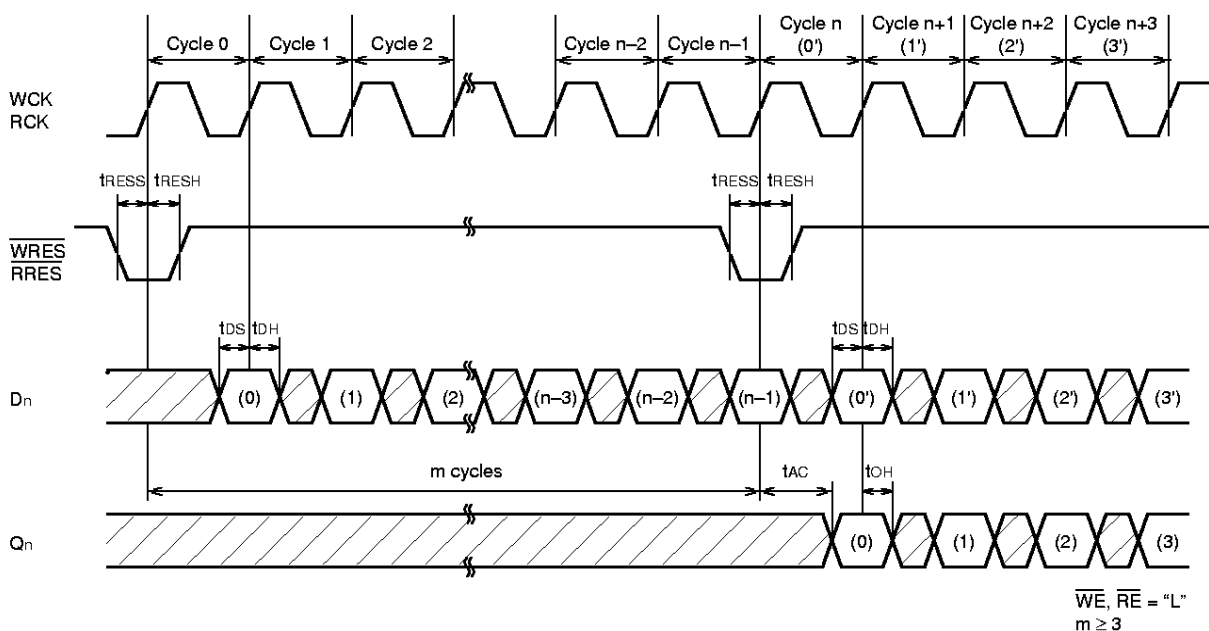
#### • 1-line (5120 bits) delay

A write input data is written into memory at the second rise edge of WCK in the cycle, and a read output data is output from memory at the first rise edge of RCK in the cycle, so that 1-line delay can be made easily.



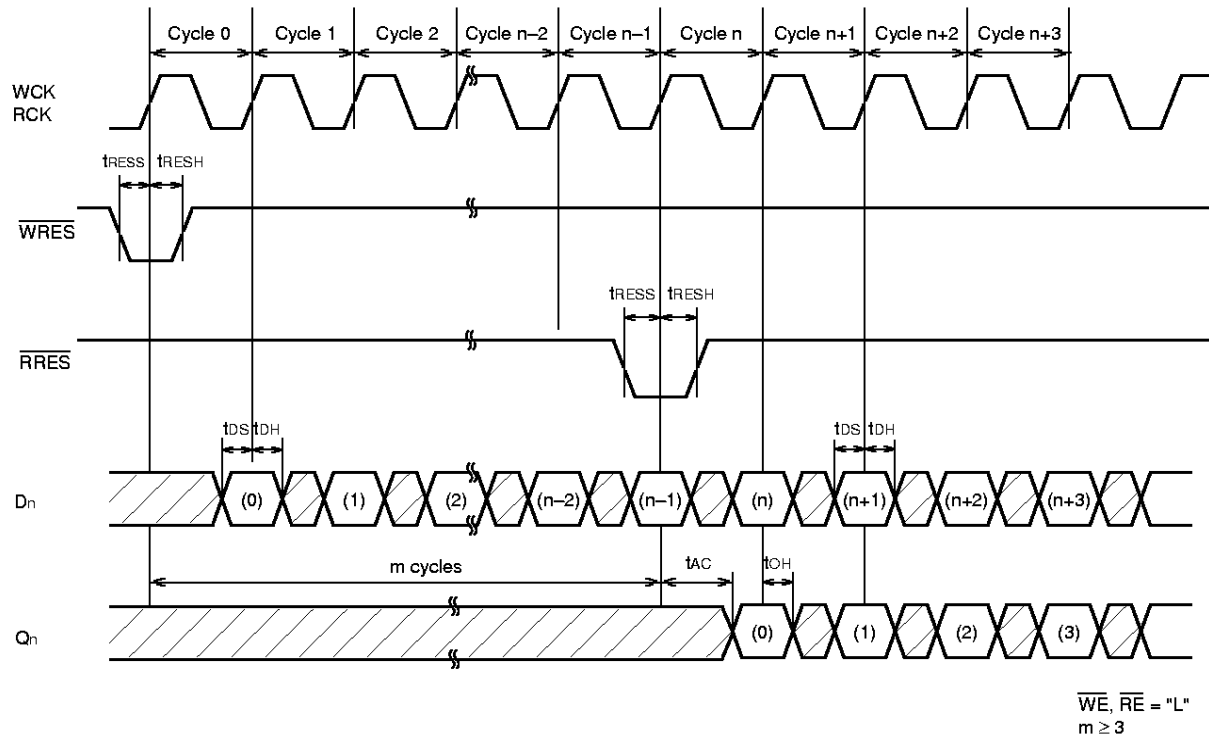
#### • N-bit delay bit

(Making a reset at a cycle corresponding to delay length)

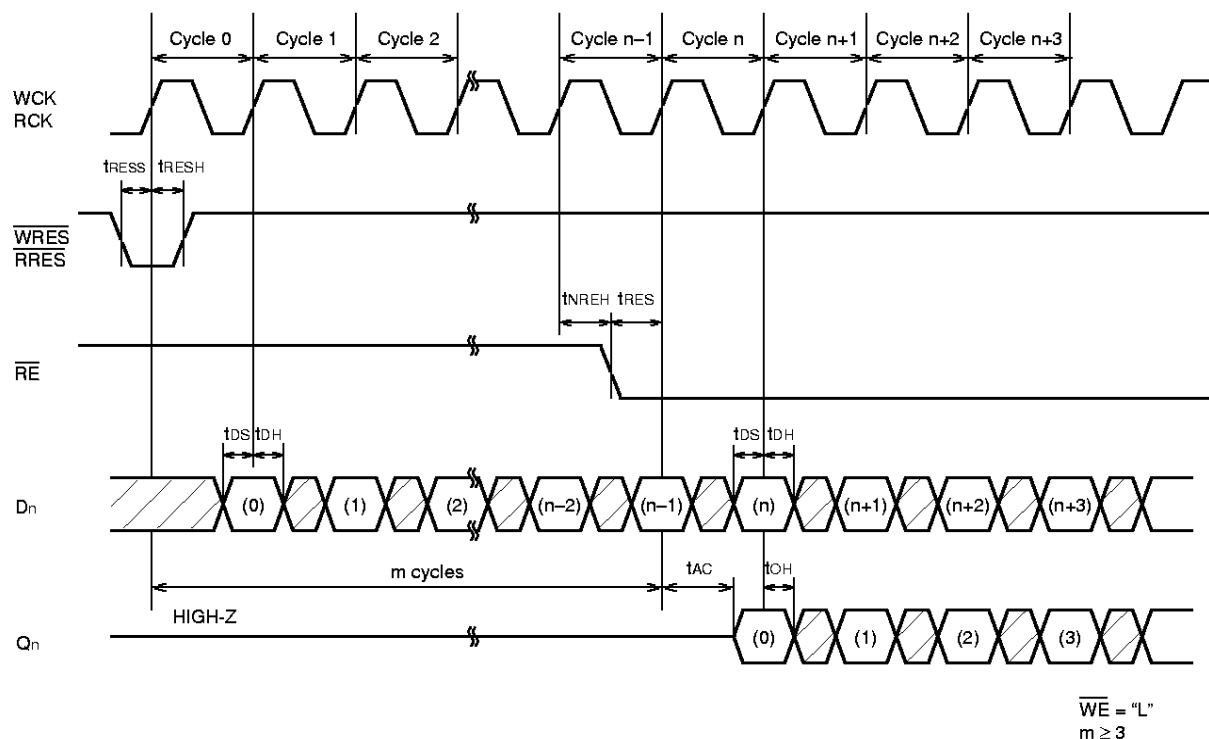




- N-bit delay 2  
(Sliding  $\overline{WRES}$  and  $\overline{RRES}$  at a cycle corresponding to delay length)



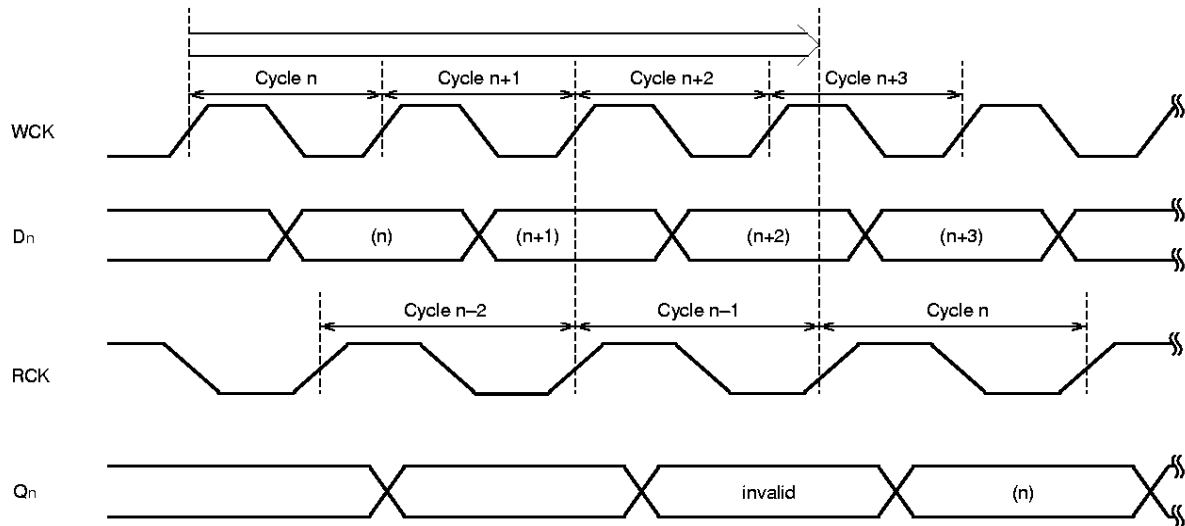
- N-bit delay 3  
(Disabling  $\overline{RE}$  at a cycle corresponding to delay length)



• Shortest read of data "n" written in cycle n

Cycle n-1 on read side should be started after end of cycle n+1 on write side

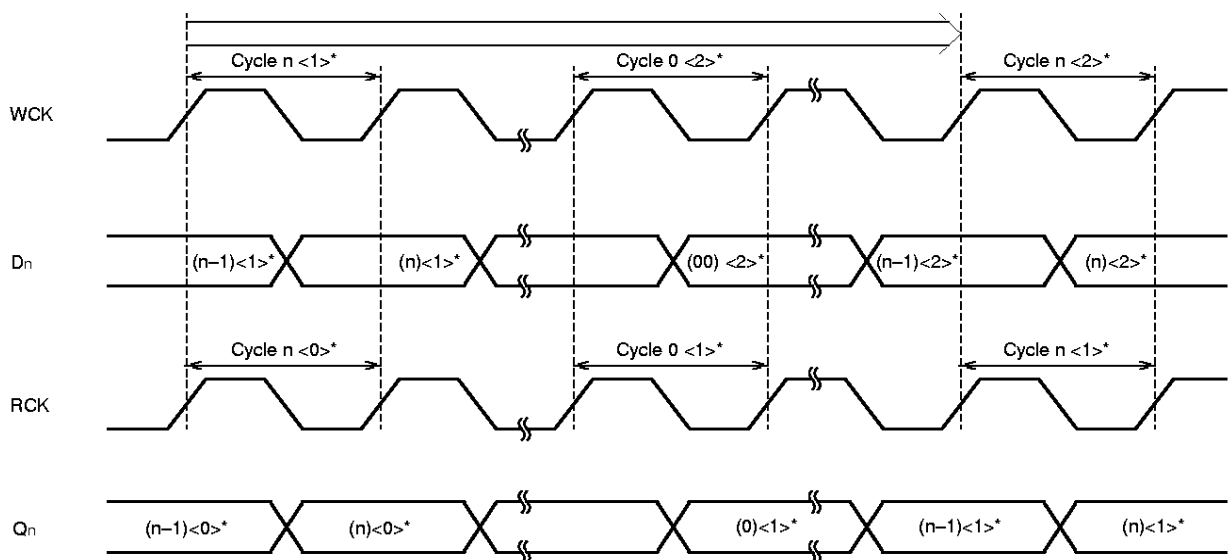
When the start of cycle n-1 on read side is earlier than the end of cycle n+1 on write side, output Q<sub>n</sub> of cycle n becomes invalid. In the figure shown below, the read of cycle n-1 is invalid.



• Longest read of data "n" written in cycle n: 1-line delay

Cycle n <1>\* on read side should be started when cycle n <2>\* on write is started

Output Q<sub>n</sub> of n cycle <1>\* can be read until the start of reading side n cycle <1>\* and the start of writing side n cycle <2>\* overlap each other.



<0>\*, <1>\* and <2>\* indicates a line value.

# APPLICATION EXAMPLE

Laplacian Filter Circuit for Correction of Resolution in the Secondary Scanning Direction.

